

Document Number: MHW8342N Rev. 3, 5/2006

<u>√Ro</u>HS

# **CATV** Amplifier Module

### Features

- Specified for up to 132-Channel Loading
- Excellent Distortion Performance
- Superior Gain, Return Loss and DC Current Stability over Temperature
- Silicon Bipolar Transistor Technology
- Unconditionally Stable Under All Load Conditions

### Applications

- CATV Systems Operating in the 40 to 870 MHz Frequency Range
- Single Module High Gain Line Amplifier in Cable TV Distribution System

### Description

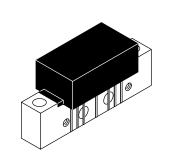
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- 24 Vdc Supply, 40 to 870 MHz, CATV High Gain Forward Amplifier Module
- Replaced MHW8342. There are no form, fit or function changes with this part replacement.
- RoHS Compliant

## MHW8342N

870 MHz 35.5 dB GAIN 132-CHANNEL CATV AMPLIFIER MODULE



### CASE 1302-01, STYLE 1

### Table 1. Maximum Ratings

Rating	Symbol	Value	Unit
RF Voltage Input (Single Tone)	V <sub>in</sub>	+ 55	dBmV
DC Supply Voltage	V <sub>CC</sub>	+28	Vdc
Operating Case Temperature Range	T <sub>C</sub>	- 20 to +100	°C
Storage Temperature Range	T <sub>stg</sub>	- 40 to +100	°C

Table 2. Electrical Characteristics (V<sub>CC</sub> = 24 Vdc, T<sub>C</sub> = +30°C, 75  $\Omega$  system unless otherwise noted)

Characteris	tic	Symbol	Min	Тур	Max	Unit
Frequency Range		BW	40	—	870	MHz
Power Gain	50 MHz 870 MHz	G <sub>p</sub>	33.2 34	34 35.5	34.8 37	dB
Slope	40 - 870 MHz	S	0.5	1.5	2.75	dB
Gain Flatness (Peak To Valley)		G <sub>F</sub>	_	0.3	0.8	dB
Return Loss — Input (Z <sub>o</sub> = 75 Ohms)	40-80 MHz 80-320 MHz 320-640 MHz 640-870 MHz	IRL	22 18 16 14	28 25 22 19	 	dB
Return Loss — Output (Z <sub>o</sub> = 75 Ohms)	40-80 MHz 80-240 MHz 240-640 MHz 640-870 MHz	ORL	22 19 17 15	28 25 22 22		dB





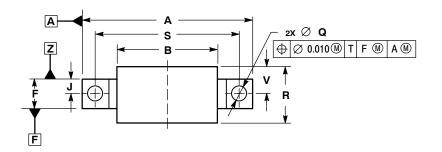
Table 2. Electrical Characteristics (V <sub>CC</sub>	$_{\rm c}$ = 24 Vdc, T <sub>C</sub> = +30°C, 75 $\Omega$ system unless otherwis	e noted) (continued)
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Characteristic		Symbol	Min	Тур	Max	Unit
Composite Second Order						dBc
(V <sub>out</sub> = +44 dBmV/ch., Worst Case)	79-Channel FLAT	CSO <sub>79</sub>	_	- 65	- 60	
(V <sub>out</sub> = +44 dBmV/ch., Worst Case)	112-Channel FLAT	CSO <sub>112</sub>		- 55	- 50	
(V <sub>out</sub> = +44 dBmV/ch., Worst Case)	132-Channel FLAT	CSO <sub>132</sub>	_	- 48	- 44	
Cross Modulation Distortion						dBc
(V <sub>out</sub> = +44 dBmV, FM = 55.25 MHz)	79-Channel FLAT	XMD <sub>79</sub>	—	- 63	- 60	
(V <sub>out</sub> = +44 dBmV, FM = 55.25 MHz)	112-Channel FLAT	XMD <sub>112</sub>	—	- 56	-52	
(V <sub>out</sub> = +44 dBmV, FM = 55.25 MHz)	132-Channel FLAT	XMD <sub>132</sub>	—	-56	-50	
Composite Triple Beat						dBc
(V <sub>out</sub> = +44 dBmV/ch., Worst Case)	79-Channel FLAT	CTB <sub>79</sub>	—	- 64	- 62	
(V <sub>out</sub> = +44 dBmV/ch., Worst Case)	112-Channel FLAT	CTB <sub>112</sub>	—	- 54	- 51	
(V <sub>out</sub> = +44 dBmV/ch., Worst Case)	132-Channel FLAT	CTB <sub>132</sub>	—	-50	- 46	
Noise Figure	50 MHz	NF	_	3.5	4.5	dB
	550 MHz		—	4.5	—	
	870 MHz		—	5.5	6.5	
DC Current		I <sub>DC</sub>	310	325	350	mA

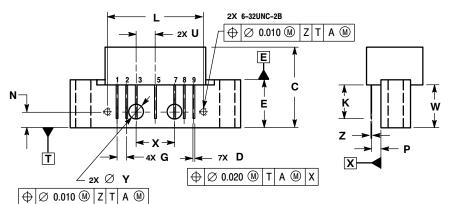
# ARCHIVE INFORMATION



### PACKAGE DIMENSIONS



# **ARCHIVE INFORMATION**



CASE 1302-01 **ISSUE E** 

NOTES: 1. DIMENSIONS ARE IN INCHES. 2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994.

	INC	HES	MILLIMETER		
DIM	MIN	MAX	MIN	MAX	
Α		1.775		45.085	
В		1.085		27.559	
С		0.840		21.336	
D	0.015	0.021	0.381	0.533	
Е	0.465	0.510	11.811	12.954	
F	0.300	0.325	7.62	8.255	
G	0.100	BSC	2.540 BSC		
J	0.156	BSC	3.962 BSC		
K	0.315	0.355	8.001	9.017	
L	1.000 BSC		25.400 BSC		
Ν	0.165 BSC		4.191 BSC		
Ρ	0.100	BSC	2.540 BSC		
Q	0.148	0.168	3.759	4.267	
R		0.600		15.24	
S	1.500	BSC	38.100 BSC		
U	0.200	BSC 5.080 BS		BSC	
V		0.250		6.350	
W	0.435		11.049		
X	0.400 BSC		10.160 BSC		
Y	0.152	0.163	3.861	4.140	
Ζ	0.009	0.011	0.229	0.279	

STYLE 1: PIN 1. RF INPUT 2. GROUND 3. GROUND 4. DELETED 5. VDC 6. DELETED 7. GROUND 8. GROUND 9. RF OUTPUT



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### USA/Europe or Locations Not Listed:

Freescale Semiconductor Technical Information Center, CH370 1300 N. Alma School Road Chandler, Arizona 85224 +1-800-521-6274 or +1-480-768-2130 support@freescale.com

### Europe, Middle East, and Africa:

Freescale Halbleiter Deutschland GmbH Technical Information Center Schatzbogen 7 81829 Muenchen, Germany +44 1296 380 456 (English) +46 8 52200080 (English) +49 89 92103 559 (German) +33 1 69 35 48 48 (French) support@freescale.com

### Japan:

Freescale Semiconductor Japan Ltd. Headquarters ARCO Tower 15F 1-8-1, Shimo-Meguro, Meguro-ku, Tokyo 153-0064 Japan 0120 191014 or +81 3 5437 9125 support.japan@freescale.com

### Asia/Pacific:

Freescale Semiconductor Hong Kong Ltd. Technical Information Center 2 Dai King Street Tai Po Industrial Estate Tai Po, N.T., Hong Kong +800 2666 8080 support.asia@freescale.com

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